## NSN 5961-01-165-4197

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Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
56.0 breakdown voltage, collector-to-base, emitter open and 18.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown
voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
8.00 amperes source cutoff current
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Contains beryllium oxide; junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
<del>-</del>
Demilitarization:
No
Fiig:
A110a0